Switch-mode Power Rectifier

Features and Benefits

- Dual Diode Construction Terminals 1 and 3 May Be Connected for Parallel Operation at Full Rating
- 45 V Blocking Voltage
- Low Forward Voltage Drop
- 175°C Operating Junction Temperature
- These are Pb-Free Devices

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight (Approximately): 1.9 Grams (TO-220)

1.5 Grams (TO-262)

- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Epoxy Meets UL 94 V-0 @ 0.125 in

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	45	V
Average Rectified Current (T _C = 130°C)	Per Device Per Diode	I _{F(AV)}	30 15	Α
Peak Repetitive Forward Current, per Diode (Square Wave, V _R = 45 V, 20 kHz)		I _{FRM}	30	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions, Halfwave, Single Phase, 60 Hz)		I _{FSM}	150	Α
Peak Repetitive Reverse Current, per Diode (2.0 μs, 1.0 kHz)		I _{RRM}	2.0	Α
Storage Temperature Range		T _{stg}	-65 to +175	°C
Operating Junction Temperature (Note 1)		T_J	-65 to +175	°C
Peak Surge Junction Temperature (Forward Current Applied)		T _{J(pk)}	175	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

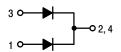
1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}.$



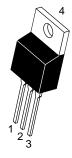
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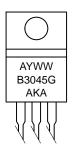
SCHOTTKY BARRIER RECTIFIER 30 AMPERES 45 VOLTS

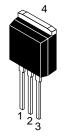


MARKING DIAGRAMS



TO-220 CASE 221A STYLE 6





I²PAK (TO-262) CASE 418D STYLE 3



A = Assembly Location

Y = Year WW = Work Week

AKA = Polarity Designator
G = Pb-Free Device

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

THERMAL CHARACTERISTICS (Per Diode)

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	1.5	°C/W

ELECTRICAL CHARACTERISTICS (Per Diode)

Characteristic	Symbol	Value	Unit
Instantaneous Forward Voltage (Note 2)	VF	0.62 0.57 0.76 0.72	V
Instantaneous Reverse Current (Note 2) (V _R = 45 Volts, T _C = 25°C) (V _R = 45 Volts, T _C = 125°C)	I _R	0.2 40	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2 Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

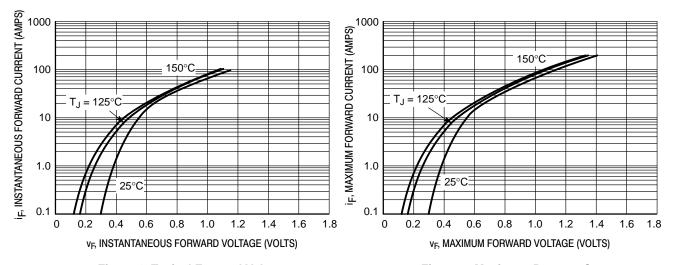


Figure 1. Typical Forward Voltage

Figure 2. Maximum Reverse Current

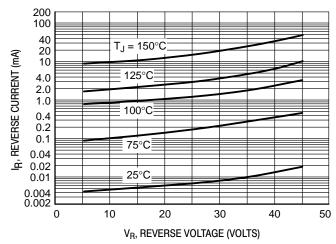
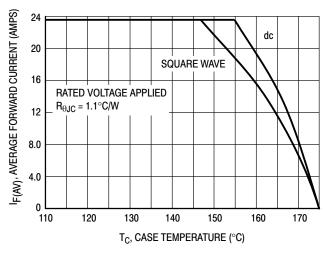


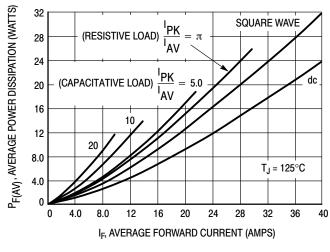
Figure 3. Typical Reverse Current



24 IF(AV), AVERAGE FORWARD CURRENT (AMPS) $R_{\theta JA} = 16^{\circ}\text{C/W}$ (With TO-220 Heat Sink) 20 $R_{\theta,JA} = 60^{\circ}C/W$ dc (No Heat Sink) 16 RATED V_R APPLIED 12 SQUARE WAVE 8.0 dc 4.0 SQUARE WAVE 0 0 20 100 120 140 160 180 TA, AMBIENT TEMPERATURE (°C)

Figure 4. Current Derating, Case

Figure 5. Current Derating, Ambient



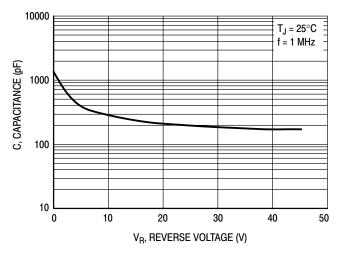


Figure 6. Forward Power Dissipation

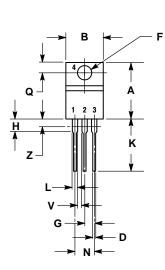
Figure 7. Capacitance

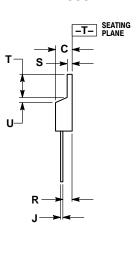
ORDERING INFORMATION

Device	Package	Shipping
MBR3045STG	TO-220 (Pb-Free)	50 Units/Rail
MBRB3045CT-1G	TO-262 (Pb-Free)	50 Units/Rail

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 ISSUE AH





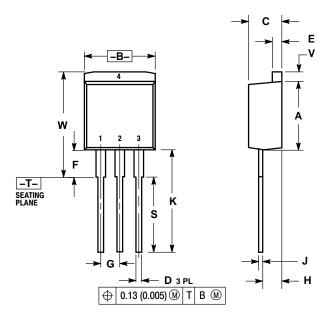
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.415	9.66	10.53
С	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 6:
 PIN 1. ANODE
 2. CATHODE
 3. ANODE
 4. CATHODE

PACKAGE DIMENSIONS

I²PAK (TO-262) CASE 418D ISSUE D



- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.335	0.380	8.51	9.65
В	0.380	0.406	9.65	10.31
С	0.160	0.185	4.06	4.70
D	0.026	0.035	0.66	0.89
E	0.045	0.055	1.14	1.40
F	0.122 REF		3.10 REF	
G	0.100 BSC		2.54	BSC
Н	0.094	0.110	2.39	2.79
J	0.013	0.025	0.33	0.64
K	0.500	0.562	12.70	14.27
S	0.390 REF		9.90	REF
٧	0.045	0.070	1.14	1.78
w	0.522	0.551	13 25	14 00

STYLE 3:

PIN 1. ANODE

- 2. CATHODE 3. ANODE
- CATHODE

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